# HMC356\* PRODUCT PAGE QUICK LINKS

Last Content Update: 02/23/2017

## COMPARABLE PARTS

View a parametric search of comparable parts.

#### EVALUATION KITS

HMC356LP3 Evaluation Board

## **DOCUMENTATION**

#### **Application Notes**

- AN-1363: Meeting Biasing Requirements of Externally Biased RF/Microwave Amplifiers with Active Bias Controllers
- Broadband Biasing of Amplifiers General Application Note
- MMIC Amplifier Biasing Procedure Application Note
- Thermal Management for Surface Mount Components General Application Note

#### **Data Sheet**

• HMC356 Data Sheet

#### TOOLS AND SIMULATIONS $\Box$

• HMC356 S-Parameter

### REFERENCE MATERIALS

#### **Quality Documentation**

- Package/Assembly Qualification Test Report: 16L 3x3mm QFN Package (QTR: 11003 REV: 02)
- Package/Assembly Qualification Test Report: LP2, LP2C, LP3, LP3B, LP3C, LP3D, LP3F, LP3G (QTR: 2014-0364)
- Package/Assembly Qualification Test Report: Plastic Encapsulated QFN (QTR: 05006 REV: 02)
- Semiconductor Qualification Test Report: PHEMT-B (QTR: 2013-00233)

#### **Technical Articles**

• Active Multipliers & Dividers to Simplify Synthesizers

#### DESIGN RESOURCES

- HMC356 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

#### DISCUSSIONS

View all HMC356 EngineerZone Discussions.

## SAMPLE AND BUY

Visit the product page to see pricing options.

#### TECHNICAL SUPPORT

Submit a technical question or find your regional support number.

### DOCUMENT FEEDBACK

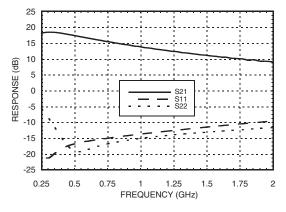
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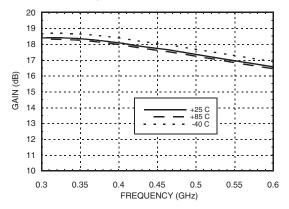




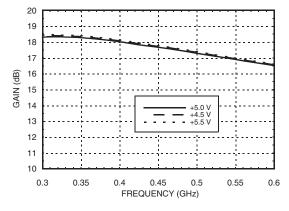
#### **Broadband Gain & Return Loss**



#### Gain vs. Temperature

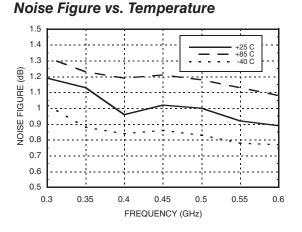


#### Gain vs. Vdd

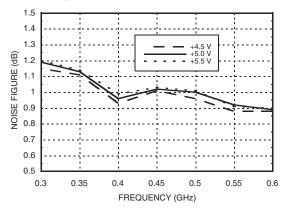


# HMC356LP3 / 356LP3E

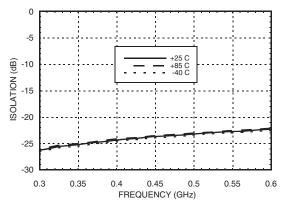
# GaAs PHEMT MMIC LOW NOISE AMPLIFIER, 350 - 550 MHz



#### Noise Figure vs. Vdd



#### **Reverse Isolation**



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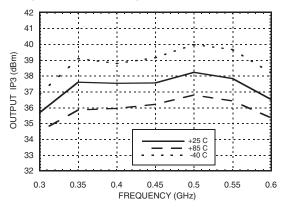
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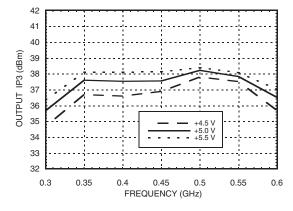


#### Input Return Loss vs. Temperature -5 RETURN LOSS (dB) +25 C +85 C -40 C -10 . . -15 -20 -25 0.3 0.35 0.4 0.45 0.5 0.55 0.6 FREQUENCY (GHz)

Output IP3 vs. Temperature

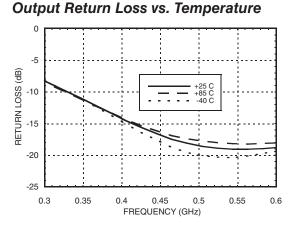


Output IP3 vs. Vdd

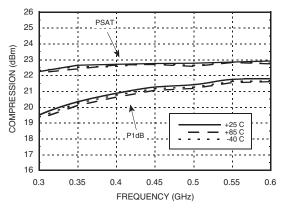


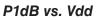
# HMC356LP3 / 356LP3E

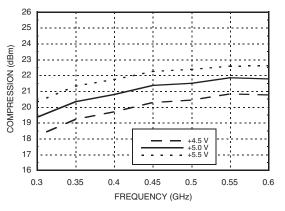
# GaAs PHEMT MMIC LOW NOISE AMPLIFIER, 350 - 550 MHz



#### P1dB & Psat vs. Temperature







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### Absolute Maximum Ratings

	•
Drain Bias Voltage (Vdd)	+8.0 Vdc
RF Input Power (RFIN)(Vdd = +5.0 Vdc)	+15 dBm
Channel Temperature	150 °C
Continuous Pdiss (T = 85 °C) (derate 14 mW/°C above 85 °C)	0.910 W
Thermal Resistance (channel to ground paddle)	71.4 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C

# HMC356LP3 / 356LP3E

# GaAs PHEMT MMIC LOW NOISE AMPLIFIER, 350 - 550 MHz

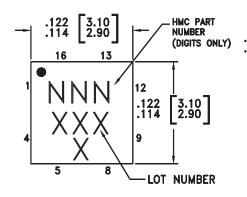
## Typical Supply Current vs. Vdd

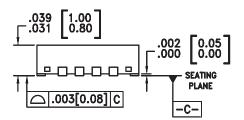
Vdd (Vdc)	Idd (mA)
+4.5	103
+5.0	104
+5.5	105



ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

## **Outline Drawing**





BOTTOM VIEW .016 [0.40] REF PIN 16 .012 0.30 .007 0.18 .008 [0.20] MIN ЧΠ Ц PIN 1 0.56 1.56 1.44 .061 hпп EXPOSED GROUND PADDLE 1.95 1.50 .077 .059 MUST BE CONNECTED TO **RF/DC GROUND** SOUARE

NOTES:

- 1. LEADFRAME MATERIAL: COPPER ALLOY
- 2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
- 3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE
- 4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM.
- PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
  6. ALL GROUND LEADS AND GROUND PADDLE MUST BE
- SOLDERED TO PCB RF GROUND.
- 7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED LAND PATTERN.

#### Package Information

	-				
Part Number Package Body		Package Body Material	Lead Finish	MSL Rating	Package Marking <sup>[3]</sup>
	HMC356LP3	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 [1]	356 XXXX
	HMC356LP3E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 <sup>[2]</sup>	<u>356</u> XXXX

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX

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# HMC356LP3 / 356LP3E

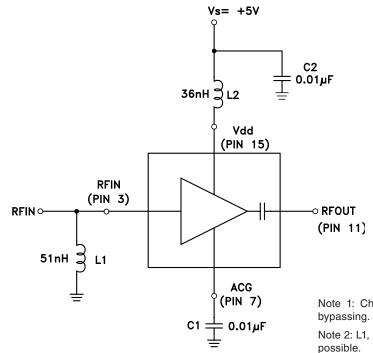
# GaAs PHEMT MMIC LOW NOISE AMPLIFIER, 350 - 550 MHz



### **Pin Descriptions**

Pin Number	Function	Description	Interface Schematic
1, 5, 8, 9, 10, 12, 13, 14	N/C	No connection necessary. These pins may be connected to RF/DC ground.	
2, 4, 6,16	GND	These pins and package ground paddle must be connected to RF/DC ground.	
3	RFIN	This pin is matched to 50 Ohms with a 51 nH inductor to ground. See Application Circuit.	RFIN O
7	ACG	AC Ground - An external capacitor of 0.01µF to ground is required for low frequency bypassing. See Application Circuit for further details.	ACG O
11	RFOUT	This pin is AC coupled and matched to 50 Ohms.	
15	Vdd	Power supply voltage. Choke inductor and bypass capacitor are required. See application circuit.	ACG O

## **Application & Evaluation PCB Circuit**



Note 1: Choose value of capacitor C1 for low frequency bypassing. A 0.01  $\mu F$  ±10% capacitor is recommended.

Note 2: L1, L2 and C1 should be located as close to pins as possible.

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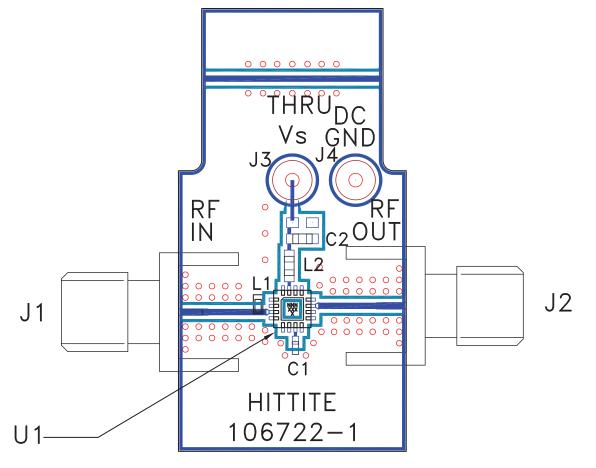


HMC356LP3 / 356LP3E

## GaAs PHEMT MMIC LOW NOISE AMPLIFIER, 350 - 550 MHz



#### **Evaluation PCB**



#### List of Materials for Evaluation PCB 107795 [1]

Item	Description
J1 - J2	PCB Mount SMA RF Connector
J3 - J4	DC Pin
C1	10,000 pF Capacitor, 0402 Pkg.
C2	10,000 pF Capacitor, 0603 Pkg.
L1	51 nH Inductor, 0402 Pkg.
L2	36 nH Inductor, 0603 Pkg.
U1	HMC356LP3 / HMC356LP3E Amplifier
PCB [2]	106722 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

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